## 20th Anniversary "Trento" Workshop on Advanced Silicon Radiation Detectors

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## Performance of irradiated TI-LGADs at 160 GeV SPS pion beams

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Trench-isolated (TI) LGADs, developed at FBK, are pixelated LGAD implementations where pads are separated by physical trenches etched within the silicon substrate and filled with a dielectric. Developed as an alternative approach to implant-based inter-pad separation (JTEs), this technology promises a dramatic reduction to dead regions, mitigating fill factor issues inherent to small-pitch pixelated LGAD matrices. Through a dedicated 160 GeV SPS pion test beam campaign, the time resolution, efficiency and inter-pad distance of Carbon Infused irradiated TI-LGADs is presented in MIP conditions. Fluences up to  $2.5 \times 10^{15}~\rm n_{eq}/cm^2$  are evaluated, for single trench implementations with varied trench width. The combined timing and tracking readout used in this study, integrating ROI triggering, sub- $\mu$ m multi-object alignment, multi-channel waveform digitization and achieving a 5-7  $\mu$ m spatial resolution through a MIMOSA26 telescope, is also reviewed. Preliminary results are discussed for temperatures of -25  $^{\circ}$ C.

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